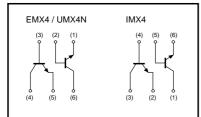
High transition frequency (dual transistors) EMX4 / UMX4N / IMX4

Features

- 1) Two 2SC3837K chips in a EMT or UMT or SMT package.
- 2) High transition frequency. (fT=1.5GHz)
- 3) Low output capacitance. (Cob=0.9pF)

Equivalent circuits



● Absolute maximum ratings (Ta=25°C)

		Unit	
Vсво	30	V	
VCEO	20	V	
Vebo	3	V	
lc	50	mA	
Da	150(TOTAL)	mW *1	
	300(TOTAL)	*2	
Tj	150	°C	
Tstg	-55 to +150	°C	
	VCEO VEBO IC PC Tj	Vceo 20 Vebo 3 Ic 50 Pc 150(TOTAL) 300(TOTAL) 150 Tj 150 Tstg -55 to +150	

*2 200mW per element must not be exceeded.

Package, marking, and packaging specifications

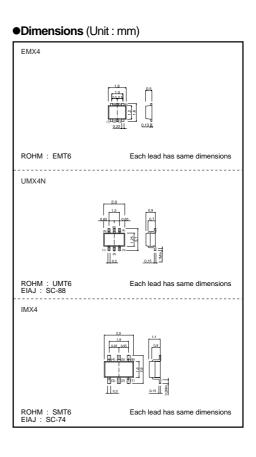
Туре	EMX4	UMX4N	IMX4	
Package	EMT6	UMT6	SMT6	
Marking	X4	X4	X4	
Code	T2R	TR	T108	
Basic ordering unit (pieces)	8000	3000	3000	

Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-base breakdown voltage	ВУсво	30	-	-	V	Ic=10µA
Collector-emitter breakdown voltage	BVCEO	20	-	-	V	Ic=1mA
Emitter-base breakdown voltage	ВVево	3	-	-	V	Ιε=10μΑ
Collector cutoff current	Ісво	-	-	0.5	μA	Vcb=15V
Emitter cutoff current	Іево	-	-	0.5	μA	VEB=2V
DC current transfer ratio	hre	56	-	180	_	Vce/lc=10V/10mA
Collector-emitter saturation voltage	VCE(sat)	-	-	0.5	V	Ic/IB=20mA/4mA
Transition frequency	fτ	600	1500	-	MHz	Vce/IE=10V/ -10mA, f=200MHz *
Output capacitance	Cob	-	0.95	1.6	pF	Vcb/f=10V/1MHz, IE=0A
Collector-base time constant	rbb'•Cc	-	6	13	ps	Vсв=10V, Ic=10mA, f=31.8MHz
Noise factor	NF	-	4.5	-	dB	Vce=12V, Ic=2mA , f=200MHz , Rg=50Ω

nsition frequency of the device

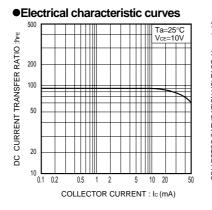
This product might cause chip aging and breakdown under the large electrified environment. Please consider to design ESD protection circuit.





EMX4 / UMX4N / IMX4

Transistors





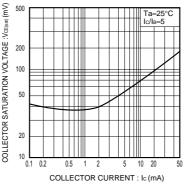


Fig.2 Collector-emitter saturation voltage vs. collector current

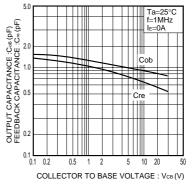
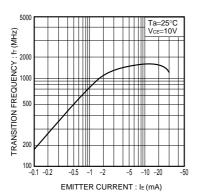
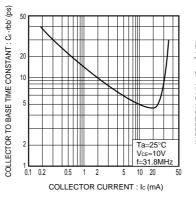
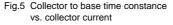


Fig.3 Capacitance vs. reverse bias voltage









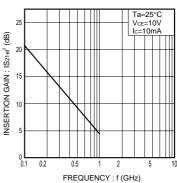


Fig.6 Insertion gain vs. frequency

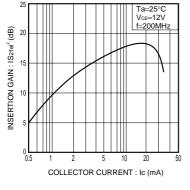
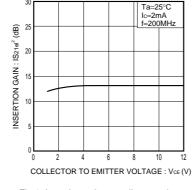
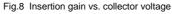
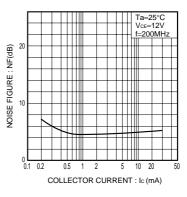


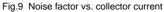
Fig.7 Insertion gain vs. collector current



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2/3

EMX4 / UMX4N / IMX4

Transistors

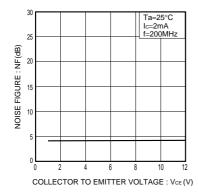


Fig.10 Noise factor vs. collector voltage



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